GL1116

0.6A Low Dropout Positive Adjustable or Fixed-Mode Regulator

Description

The GL1116 is a low dropout at positive adjustable or fixed-mode regulator with minimum of 0.6A output current capability. The product is specifically designed to provide well-regulated supply for low voltage IC applications such as high-speed bus termination and low current 3.3V logic supply. GL1116 is also well suited for other applications such as VGA cards. GL1116 is guaranteed to have lower than 1.3V dropout at full load current making it ideal to provide well regulated outputs of 1.25V to 5.0V with up to 12V input supply.

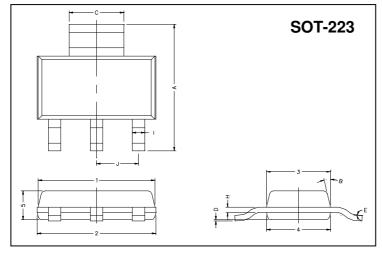
Features

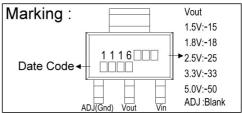
- 1.3Vmaximum dropout full load current
- Fast transient response
- · Output current limiting
- Built-in thermal shutdown
- Good noise rejection
- 3-Terminal Adjustable or Fixed 1.5V,1.8V,2.5V,3.3V,5.0V

Applications

- PC peripheral
- Communication

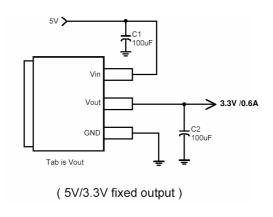
Package Dimensions

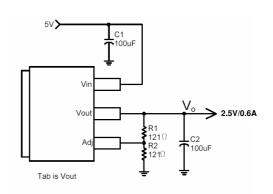




REF.	Millimeter		REF.	Millimeter		
	Min.	Max.	rLI.	Min.	Max.	
Α	6.70	7.30	В	13°TYP.		
С	2.90	3.10	J	2.30 REF.		
D	0.02	0.10	1	6.30	6.70	
Е	0°	10°	2	6.30	6.70	
	0.60	0.80	3	3.30	3.70	
Н	0.25	0.35	4	3.30	3.70	
			5	1.40	1.80	

Typical Circuit



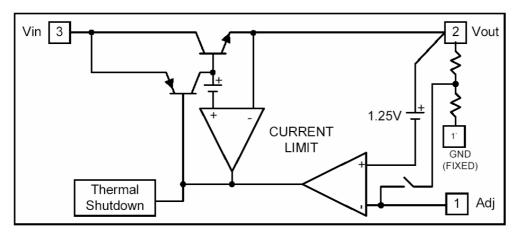


(5V/2.5V ADJ output)

Note:
$$V_o = V_{REF} * (1 + \frac{R_2}{R_4})$$

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Block Diagram



Pin Descriptions

Name	I/O	Pin#	Function
Adj (GND)		1	A resistor divider from this pin to the Vout pin and ground sets the output voltage (Ground only for fixed mode)
Vout	0	2	The output of the regulator. A minimum of 10uF capacitor $(0.15\Omega \le ESR \le 20\Omega)$ must be connected from this pin to ground to insure stability.
Vin	1	3	The input pin of regulator. Typically a large storage capacitor $(0.15\Omega \le ESR \le 20\Omega)$ is connected from this pin to ground to insure that the input voltage does not sag below the minimum dropout voltage during the load transient response. This pin must always be 1.3V higher than Vout in order for the device to regulate properly.

Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit
VIN	DC Supply Voltage	-0.3 to 12	V
Po	Power Dissipation	Internally Limited	
Tst	Storage Temperature	-65 ~ + 150	$^{\circ}\!\mathbb{C}$
Тор	Operating Junction Temperature Range	0 ~ + 150	$^{\circ}\mathbb{C}$

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Electrical Characteristics

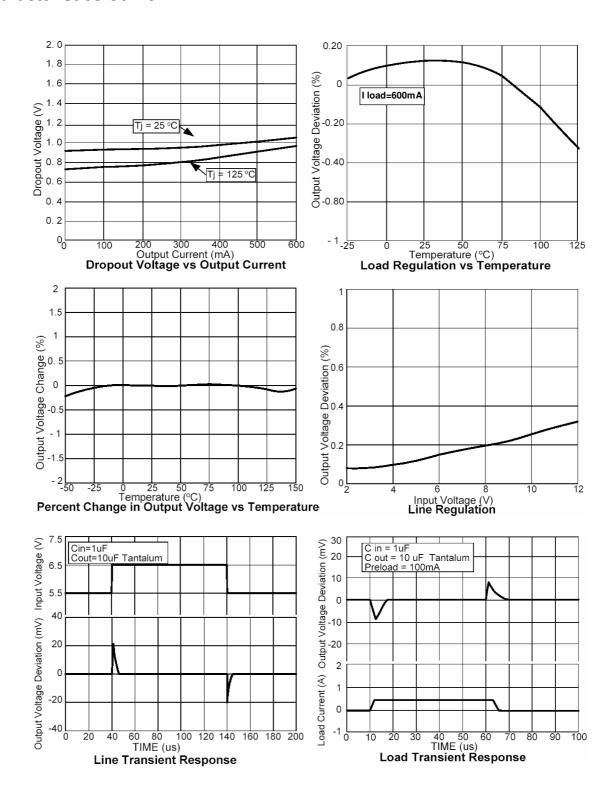
Parameter	Conditions			Тур	Max	Unit
Reference Voltage	GL1116ADJ	Io=10mA, TJ=25°C, (VIN-VOUT)=1.5V	1.225	1.250	1.275	V
	GL1116-1.5	Io=10mA, TJ=25°C, 3.0V≤ VIN ≤12V	1.470	1.500	1.530	V
	GL1116-1.8	Io=10mA, TJ=25°C, 3.3V≤ V _{IN} ≤12V	1.764	1.800	1.836	٧
Output Voltage	GL1116-2.5	Io=10mA, TJ=25°C, 4.0V≤ V _{IN} ≤12V	2.450	2.500	2.550	٧
	GL1116-3.3	Io=10mA, TJ=25°C, 4.8V≤ V _{IN} ≤12V	3.235	3.300	3.365	V
	GL1116-5.0	Io=10mA, TJ=25°C, 6.5V≤ V _{IN} ≤12V	4.900	5.000	5.100	V
Line Regulation	GL1116-XXX	Io=10mA, Vout+1.5V< VIN <12V, TJ=25℃	-	-	0.2	%
	GL1116ADJ	V _{IN} =3.3V, Vadj=0, 0mA< lo <0.6A, T _J =25°C (Note 1,2)	-	-	1	%
	GL1116-1.5	VIN=3.0V, 0mA< Io <0.6A, TJ=25 $^{\circ}$ C (Note 1,2)	-	12	15	mV
Load Regulation	GL1116-1.8	VIN=3.3V, 0mA< Io <0.6A, TJ=25°C (Note 1,2)	-	15	18	mV
	GL1116-2.5	VIN=4.0V, 0mA< Io <0.6A, TJ=25°C (Note 1,2)	-	20	25	mV
	GL1116-3.3	VIN=5.0V, 0mA< Io <0.6A, TJ=25°C (Note 1,2)	-	26	33	mV
	GL1116-5.0	VIN=8.0V, 0mA< Io <0.6A, TJ=25°C (Note 1,2)	-	40	50	mV
Dropout Voltage (VIN-VOUT)	GL1116-XXX	Io=0.6A (Δ VOUT =0.1% VOUT)	-	1.1	1.3	V
Current Limit	GL1116-XXX	VIN-VOUT=5V	0.7	-	-	Α
Minimum Load Current	Adjustable model	Vin=5V	-	5	10	mA
Adjust Pin Current	Adjustable model	Vin=12V, Io=10mA	-	50	100	uA
Quiescent Current	fixed model	Vin=12V, Io=0mA	-	-	12	mA
Thermal Regulation	Ta=25°C,30ms pulse		-	0.008	0.04	%/W
Dinale Dejection	F=120HZ,Cout=25uF Tantalum, Iout=0.6A			•	•	
Ripple Rejection	GL1116-XXX	VIN=VOUT+3V	-	60	70	dB
Temperature Stability	Io=10mA		-	0.5	-	%
θJA Thermal Resistance Junction-to-Ambient(No heat sink ;No air flow)			-	117	-	°C/W
Өлс Thermal Resistance Junction-to-Case Control Circuitry/Power Transistor		-	15	-	°C/W	

Note 1: See thermal regulation specifications for changes in output voltage due to heating effects. Line and load regulation are measured at a constant junction temperature by low duty cycle pulse testing. Load regulation is measured at the output lead =1/18" from the package.

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Note 2: Line and load regulation are guaranteed up to the maximum power dissipation of 3W. Power dissipation is determined by the difference between input and output and the output current. Guaranteed maximum power dissipation will not be available over the full input/output range.

Characteristics Curve



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